MCT2200X, MCT2201X, MCT2202X,
MCT2200, MCT2201, MCT2202

OPTICALLY COUPLED ISOLATOR PHOTOTRANSISTOR OUTPUT

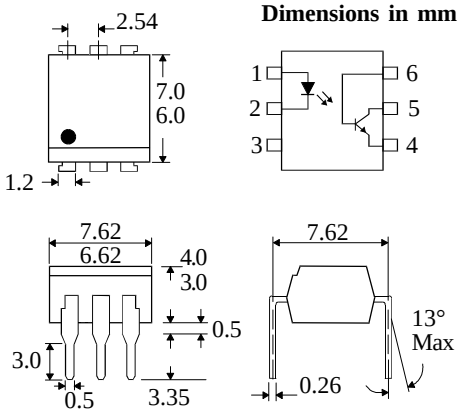
ROHS COMPLIANT

APPROVALS

- UL recognised, File No. E91231

'X' SPECIFICATION APPROVALS

- VDE 0884 in 3 available lead forms : -
  - STD
  - G form
  - SMD approved to CECC 00802
- Certified to EN60950 by the following Test Bodies :-
  Nemko - Certificate No. P96101299
  Fimko - Registration No. 190469-01..22
  Semko - Reference No. 9620076 01
  Demko - Reference No. 305567



DESCRIPTION

The MCT220_ series of optically coupled isolators consist of an infrared light emitting diode and NPN silicon photo transistor in a standard 6 pin dual in line plastic package.

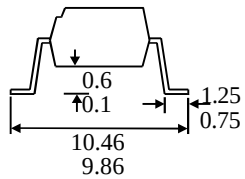
FEATURES

- Options :-
  10mm lead spread - add G after part no.
  Surface mount - add SM after part no.
  Tape&reel - add SMT&R after part no.
- High Isolation Voltage ($5.3kV_{RMS}$,$7.5kV_{PK}$)
- All electrical parameters 100% tested
- Custom electrical selections available

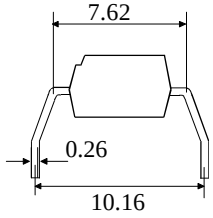
APPLICATIONS

- DC motor controllers
- Industrial systems controllers
- Measuring instruments
- Signal transmission between systems of different potentials and impedances

OPTION SM
SURFACE MOUNT



OPTION G



ABSOLUTE MAXIMUM RATINGS
(25°C unless otherwise specified)

Storage Temperature	-55°C to + 150°C
Operating Temperature	-55°C to + 100°C
Lead Soldering Temperature (1/16 inch (1.6mm) from case for 10 secs)	260°C

INPUT DIODE

Forward Current	60mA
Reverse Voltage	6V
Power Dissipation	105mW

OUTPUT TRANSISTOR

Collector-emitter Voltage BV_{CEO}	30V
Collector-base Voltage BV_{CBO}	70V
Emitter-base Voltage BV_{EBO}	5V
Power Dissipation	160mW

POWER DISSIPATION

Total Power Dissipation	200mW
(derate linearly 2.67mW/°C above 25°C)	

ISOCOM COMPONENTS LTD
Unit 25B, Park View Road West,
Park View Industrial Estate, Brenda Road
Hartlepool, Cleveland, TS25 1YD
Tel: (01429) 863609 Fax :(01429) 863581

ELECTRICAL CHARACTERISTICS (T_A= 25°C Unless otherwise noted)

PARAMETER		MIN	TYP	MAX	UNITS	TEST CONDITION
Input	Forward Voltage (V_F)		1.2	1.5	V	I_F = 20mA
	Reverse Voltage (V_R)	3			V	I_R = 10µA
	Reverse Current (I_R)			10	µA	V_R = 3V
Output	Collector-emitter Breakdown (BV_{CEO}) (note 2)	30			V	I_C = 1mA
	Collector-base Breakdown (BV_{CBO})	70			V	I_C = 100µA
	Emitter-base Breakdown (BV_{EBO})	5			V	I_E = 100µA
	Collector-emitter Dark Current (I_{CEO})			50	nA	V_{CE} = 10V
Coupled	Current Transfer Ratio (CTR)					
	MCT2200	20			%	10mA I_F , 5V V_{CE}
	MCT2201	100			%	
	MCT2202	63		125	%	
	Collector-emitter Saturation Voltage $V_{CE(SAT)}$			0.4	V	10mA I_F , 2.5mA I_C
	Input to Output Isolation Voltage V_{ISO}	5300			V_{RMS}	See note 1
		7500			V_{PK}	See note 1
	Input-output Isolation Resistance R_{ISO}	$5x10^{10}$			Ω	V_{IO} = 500V (note 1)
	Turn-on Time t_{ON}			10	µs	V_{CC} = 5V , R_L = 100Ω,
	Turn-off Time t_{OFF}			10	µs	I_C= 2mA, (fig 1)

Note 1 Measured with input leads shorted together and output leads shorted together.
Note 2 Special Selections are available on request. Please consult the factory.

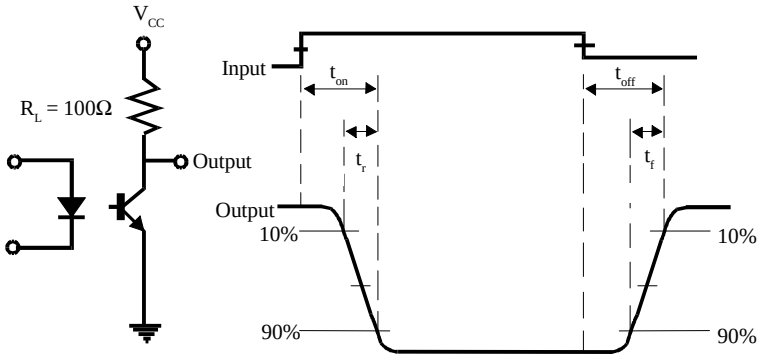
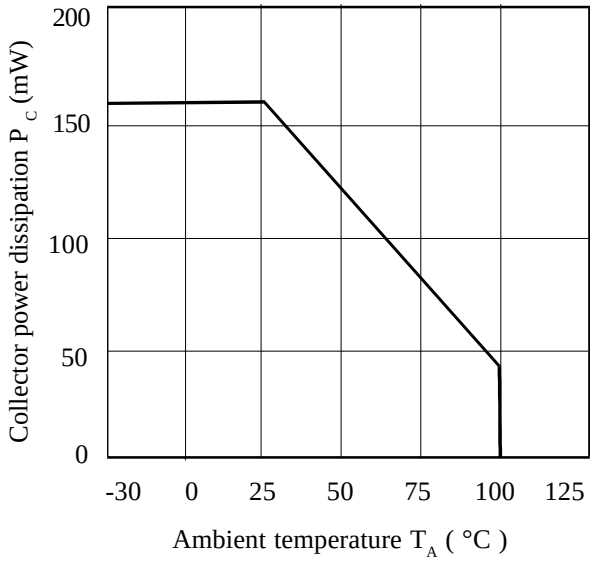
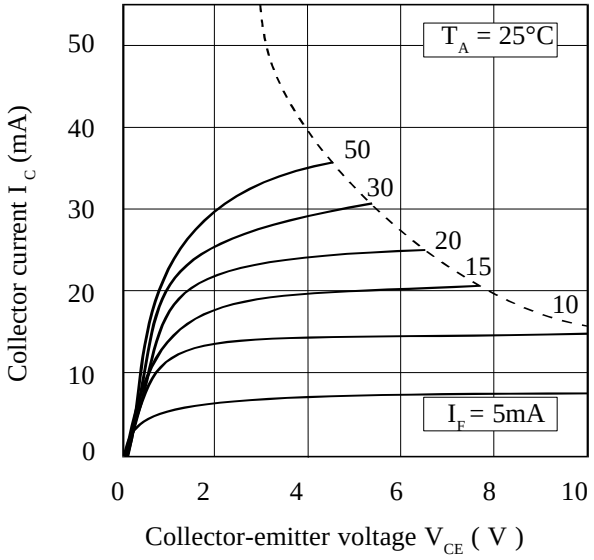


FIG 1

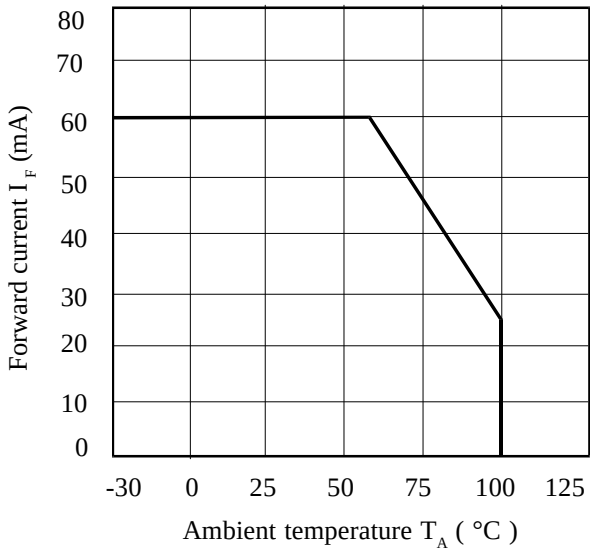
Collector Power Dissipation vs. Ambient Temperature



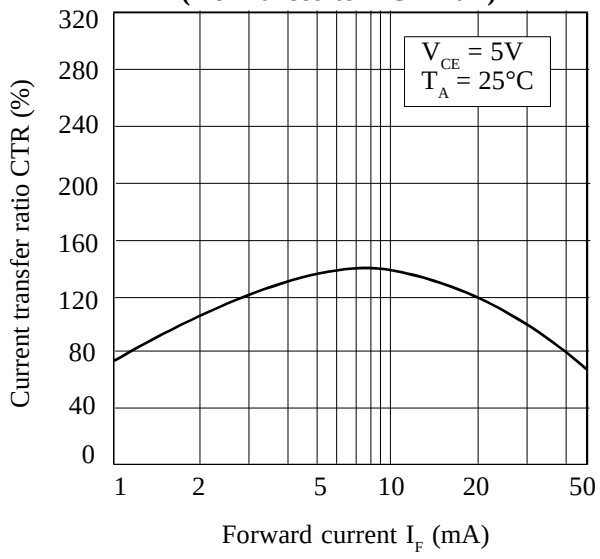
Collector Current vs. Collector-emitter Voltage (normalised to MCT2201)



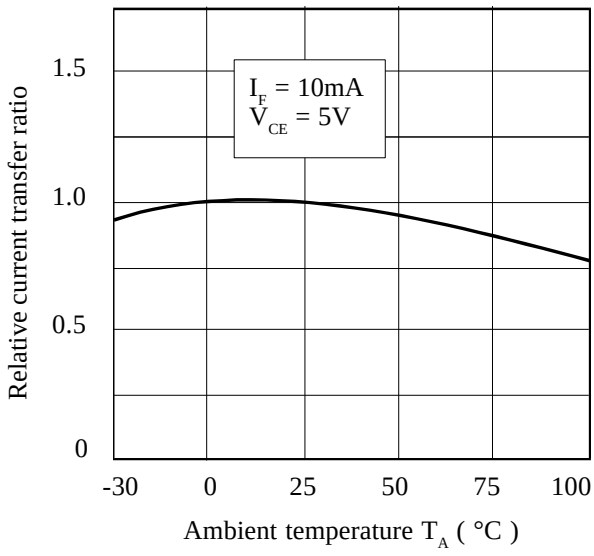
Forward Current vs. Ambient Temperature



Current Transfer Ratio vs. Forward Current (normalised to MCT2201)



Relative Current Transfer Ratio vs. Ambient Temperature



Collector-emitter Saturation Voltage vs. Ambient Temperature